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Silicon-on-Insulator Ring-Shaped Photonic Crystal Waveguides for Refractive Index Sensing

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Abstract: We present an integrated refractive index sensor based on a ring-shaped photonic crystal waveguide. We measured the shift in cut-off wavelength for different ambient refractive indices and we observed a sensitivity of \(\Delta \lambda / \Delta n = 110\text{nm/RIU}\).

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1. Introduction

The application of a refractive index (RI) sensor has gained a high degree of interest within the last decade since it can be applied to measure very small changes in temperature, pressure, humidity, chemical composition, etc. Many integrated optical sensors based on Mach-Zehnder interferometers [1], directional couplers [2], micro-rings [3], and disk resonators [4] can be made compact and integrated with both optical and electric components onto one single chip and have already been demonstrated. Recently, ultra-compact and highly sensitive sensors based on planar photonic crystal waveguides (PhCW) [5] and cavities [6] fabricated on silicon-on-insulator (SOI) wafers have also been demonstrated for e.g. bio-sensing. Here, we present an integrated RI sensor based on a ring-shaped photonic crystal waveguide (RPhCW) [7] which provides higher sensitivity than RI sensors based on PhCW with circular holes [5]. We experimentally demonstrated a sensitivity of \(\Delta \lambda / \Delta n = 110\text{nm/RIU}\) for the device.

2. Design and simulation

The proposed RPhCW sensor consists of a hexagonal lattice (pitch \(\Lambda\)) of ring-shaped holes which are defined by their outer \((R_o)\) and inner \((R_i)\) radii. As illustrated in Fig. 1(left), the RPhCW is patterned in a 340-nm thick top silicon layer of a SOI chip, and a W1 RPhCW was formed by omitting one row of the holes. This line defect introduces waveguide modes within the photonic band gap (PBG) as shown in Fig. 1(right). The band diagram is also presented for the RPhCW with \(R_o=0.384\Lambda\) and \(R_i=0.21\Lambda\) for two different ambient RI with \(n=1\) (blue) and \(n=1.1\) (red). It is seen that as the ambient RI increases, the even waveguide mode denoted as a solid continuous line is pulled down to lower frequencies which makes the cut-off wavelength red-shift in the transmission spectra. This property of the RPhCW is used as the sensor mechanism.

Figure 2(a) shows the quasi transverse-electric (TE) mode transmission spectra calculated by three-dimensional (3D) finite-difference time-domain (FDTD) modelling. Spectra were calculated for four ambient RIs, i.e., air \((n=1)\), water \((n=1.315)\), ethanol \((n=1.344)\) and isopropanol (IPA) \((n=1.363)\) [8]. It is seen that the cut-off wavelength shifts to longer wavelength with increasing ambient RI. The 3D simulation was performed using the MIT Photonic Bands software both for the RPhCW and a conventional PhCW to make a comparison on sensitivity. The geometrical parameters of \(R_o=0.324\Lambda\) for the conventional PhCW was used to ensure the same air filling factor as the RPhCW.
Figure 2(b) shows the cut-off wavelength shift against ambient RI change for two different waveguides. From the simulation, we find that the sensitivities of the PhCW and the RPhCW are 63 nm/RIU and 128 nm/RIU, respectively. The sensitivity of the RPhCW is twice as large as that of the conventional PhCW. Since the sensitivity is determined by the overlap between the optical field of the waveguide and the ambient, we also compared the mode field distribution of the two waveguide structures at the same wavevector of 0.3 ($kA/2\pi$). From the Fig 2(c), one can find that the mode in the PhCW mainly penetrates only into the two rows of holes adjacent to the waveguide core while the mode in the RPhCW penetrates highly into the cladding of the waveguide. Besides, the intensity of the mode field tends to be more localized in the ring-shaped holes of the RPhCW. Therefore, a larger overlap between the optical field and the ambient in RPhCW can be expected, which results in a higher sensitivity. Furthermore, we have also investigated the RPhCWs with different ring-gap widths ($R_o-R_i$) under water infiltration, as shown in the inset of Fig. 2(b). It is found that the sensitivity can be further increased by using narrower ring-gap widths.

3. Fabrication

The RPhCW sensor was fabricated in SOI material having a top silicon thickness of 340 nm and 1 μm of buried silicon dioxide. Diluted (1:1 in anisole) electron-beam resist ZEP520A was spun onto the wafer to create a ~110 nm thick masking layer. RPhCWs were defined in the ZEP520A layer by utilizing electron-beam lithography (JEOL JBX-9300FS). The patterns were subsequently transferred to the top silicon layer by employing inductively coupled plasma reactive ion etching (ICP-RIE). We fabricated RPhCWs with a fixed lattice constant ($A=405 \text{ nm}$) and different ring-gap widths. Figure 3(a) shows the scanning electron micrograph (SEM) image for a RPhCW. A 20 μm long RPhCW was butt-coupled to 450 nm wide access ridge waveguides at both edges, one of which is shown in Fig. 3(b). The ridge waveguides were tapered to the edges of the sample for better mode matching with the lensed fibers used in the characterization. A detailed image for the ring-shaped holes with the smallest gap that can be fabricated without shape degradation is shown in Fig. 3(c).

4. Measurement

Light transmission experiment was performed, where light from a tunable laser source (1520 - 1620 nm) was launched into the sample and collected by an optical spectral analyzer to record the transmission spectrum. The polarization of the input light was adjusted to the quasi-TE mode with a fiber polarization controller.
We tested the waveguide sensor with infiltrations of air, de-ionized (DI) water, ethanol and IPA. Figure 4(a) shows the recorded transmission spectra for a fabricated RPhCW with \( R_o=160\,\text{nm} \) and \( R_i=90\,\text{nm} \). The measured curves in air, DI water, ethanol and IPA are denoted with the black, red, blue and green solid lines, respectively. The cut-off wavelength was read out at the transmission of -35dB as shown with the dashed line in Fig. 4(a). The cut-off wavelength of the RPhCW shifted by 25.2nm, 28.3nm and 33.8nm relative to that with air infiltration. As a comparison, we repeated the measurement for a conventional PhCW with the same air filling factor (\( R=123\,\text{nm}, \; \Lambda=380\,\text{nm} \)). With infiltration of the same liquids, the cut-off wavelength of the PhCW shifted by 17.8nm (water), 20.3nm (ethanol) and 21.9nm (IPA). Thus, the RPhCW offers higher sensitivity.

Figure 4(b) shows the change of the cut-off wavelength with different ambient RIs. It is seen that the measured and simulated results are consistent for the PhCW, but there exists a small discrepancy for the RPhCW. This is probably because the RPhCW was only partially infiltrated by those liquids due to the narrow gaps of the rings and the liquid surface tension. Furthermore, the sensitivity of the RPhCW with different ring-gap widths with IPA infiltration was measured, as shown in the inset of Fig. 4(b). We observed the largest cut-off wavelength shift of 40nm for the RPhCW with 90nm ring gap. This corresponds to a sensitivity of \( \Delta \lambda/\Delta n=110\,\text{nm/RIU} \). However, contrary to the numerical prediction, the sensitivity does not increase when decreasing the ring-gap width. One possible reason is that the infiltration becomes more difficult for a narrower gap. Additionally, the silicon material in the narrower ring-shaped holes (<90nm) may only have been partially etched due to the RIE lag effect. The incomplete etching for the RPhCW is detrimental as predicted by our simulation. This also makes infiltration of liquid more difficult which will result in a reduced sensitivity. To further improve the sensitivity, slight over etching for RPhCWs with narrow ring-gap width is necessary, and a flow-injection system [9] could be used to facilitate the liquid infiltration.

![Fig. 4. (a) Measured transmission spectra of the RPhCW \( R_o=160\,\text{nm} \), \( R_i=90\,\text{nm} \) and \( \Lambda=405\,\text{nm} \) with different infiltrations. (b) Measured cut-off wavelength shift with different ambient RI (open circles and open squares) and different ring-gap width with infiltration of IPA (inset).](image)

5. Conclusion

We have demonstrated an RPhCW-based RI sensor in SOI material. We have reported a sensitivity of 110nm/RIU which is nearly twice as large as that of the conventional PhCW-based RI sensor. We believe the RPhC structure is very promising for future sensing applications.

6. Reference